

0.8 Amp. Glass Passivated Avalanche Ultrafast Recovery Rectifier

<p>Dimensions in mm.</p> <p>DO-41-MINI (Plastic)</p>	<p>Voltage 50 to 400 V.</p> <p>Current 0.8 A at 25 °C.</p> <p></p>
<p>Mounting instructions</p> <ol style="list-style-type: none"> Min. distance from body to soldering point, 4 mm. Max. solder temperature, 350 °C. Max. soldering time, 3.5 sec. Do not bend lead at a point closer than 2 mm. to the body. 	<ul style="list-style-type: none"> • Glass Passivated Junction • High current capability • The plastic material carries U/L recognition 94 V-0 • Terminals: Axial Leads • Polarity: Color band denotes cathode

Maximum Ratings, according to IEC publication No. 134

		EGP08A	EGP08B	EGP08D	EGP08F	EGP08G
	Marking Code	L1	L2	L3	L4	L5
V_{RRM}	Peak Recurrent reverse voltage (V)	50	100	200	300	400
V_{RMS}	Maximum RMS voltage	35	70	140	210	280
V_{DC}	Maximum DC blocking voltage	50	100	200	300	400
$I_{F(AV)}$	Forward current at Tamb = 25 °C			0.8 A		
I_{FRM}	Recurrent peak forward current			8 A		
I_{FSM}	8.3 ms. peak forward surge current (Jedec Method)			25 A		
t_{rr}	Max. reverse recovery time from $I_F = 0.5 \text{ A} ; I_R = 1 \text{ A} ; I_{RR} = 0.25 \text{ A}$			50 ns		
C_j	Typical Junction Capacitance at 1 MHz and reverse voltage of $4V_{DC}$			15 pF		
T_j	Operating temperature range			- 65 to + 150 °C		
T_{stg}	Storage temperature range			- 65 to + 150 °C		
E_{RSM}	Maximum non repetitive peak reverse avalanche energy $I_R = 0.5 \text{ A} ; T_j = 25 \text{ °C}$			15 mJ		

Electrical Characteristics at Tamb = 25 °C

V_F	Max. forward voltage drop at $I_F = 0.8 \text{ A}$	0.95 V	1.25 V
I_R	Max. reverse current at V_{RRM} at 25 °C at 150 °C	5 μA 50 μA	
R_{thj-a} R_{thj-a}	MAXIMUM THERMAL RESISTANCE Junction-Ambient. With Heatsink. Junction-Ambient. In P.C.B.	45 °C/W 100 °C/W	

Rating And Characteristic Curves

